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[TPCC8005-H\(TE12LQM](#)

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TOSHIBA

TPCC8005-H

TOSHIBA Field Effect Transistor Silicon N-Channel MOS Type (U-MOS -H)

TPCC8005-H

High-Efficiency DC-DC Converter Applications

Unit: mm

Notebook PC Applications

Portable Equipment Applications

- Small footprint due to a small and thin package
- High-speed switching
- Small gate charge: $Q_{SW} = 9.1 \text{ nC}$ (typ.)
- Low drain-source ON-resistance:

$$R_{DS(\text{ON})} = 5.2 \text{ m}\Omega \text{ (typ.)} \quad (V_{GS} = 4.5 \text{ V})$$

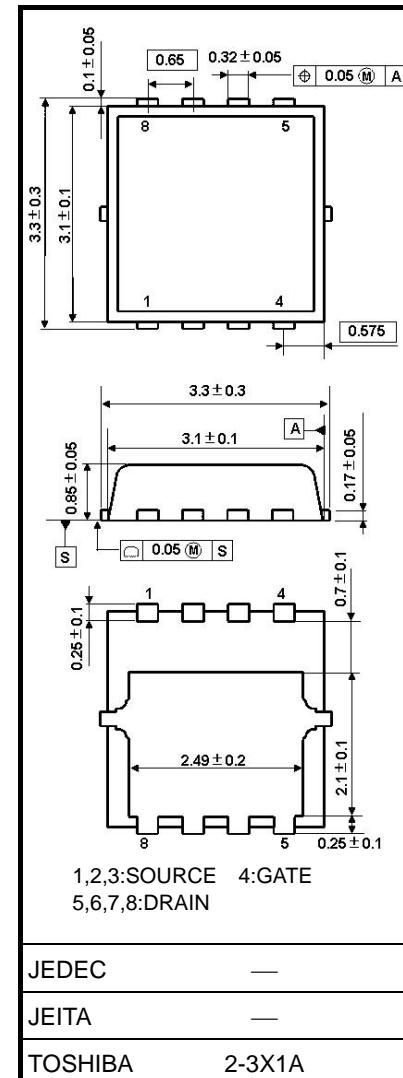
- High forward transfer admittance: $|Y_{fs}| = 79 \text{ S}$ (typ.)
- Low leakage current: $I_{DSS} = 10 \mu\text{A}$ (max) ($V_{DS} = 30 \text{ V}$)
- Enhancement mode: $V_{th} = 1.3$ to 2.3 V ($V_{DS} = 10 \text{ V}$, $I_D = 0.5 \text{ mA}$)

Absolute Maximum Ratings ($T_a = 25^\circ\text{C}$)

Characteristic	Symbol	Rating	Unit
Drain-source voltage	V_{DSS}	30	V
Drain-gate voltage ($R_{GS} = 20 \text{ k}\Omega$)	V_{DGR}	30	V
Gate-source voltage	V_{GSS}	± 20	V
Drain current	DC (Note 1)	I_D	A
	Pulsed (Note 1)	I_{DP}	
Drain power dissipation ($T_c = 25^\circ\text{C}$)	P_D	30	W
Drain power dissipation ($t = 10 \text{ s}$) (Note 2a)	P_D	1.9	W
Drain power dissipation ($t = 10 \text{ s}$) (Note 2b)	P_D	0.7	W
Single-pulse avalanche energy (Note 3)	E_{AS}	176	mJ
Avalanche current	I_{AR}	26	A
Repetitive avalanche energy ($T_c = 25^\circ\text{C}$) (Note 4)	E_{AR}	2.74	mJ
Channel temperature	T_{ch}	150	°C
Storage temperature range	T_{stg}	-55 to 150	°C

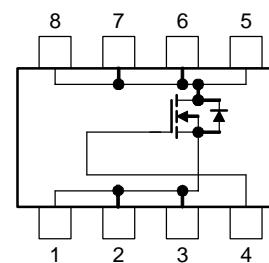
Note: For Notes 1 to 4, refer to the next page.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc.).



Weight: 0.02 g (typ.)

Circuit Configuration



This transistor is an electrostatic-sensitive device. Handle with care.

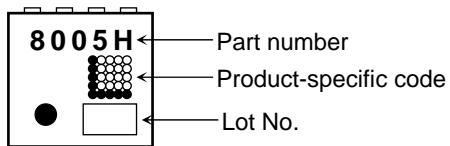
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Thermal Characteristics

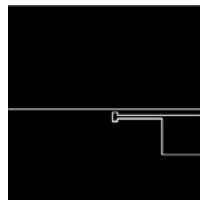
Characteristic	Symbol	Max	Unit
Thermal resistance, channel to case ($T_c = 25^\circ\text{C}$)	$R_{th} (\text{ch-c})$	4.2	$^\circ\text{C/W}$
Thermal resistance, channel to ambient ($t = 10 \text{ s}$) (Note 2a)	$R_{th} (\text{ch-a})$	66	$^\circ\text{C/W}$
Thermal resistance, channel to ambient ($t = 10 \text{ s}$) (Note 2b)	$R_{th} (\text{ch-a})$	180	$^\circ\text{C/W}$

Marking (Note 5)



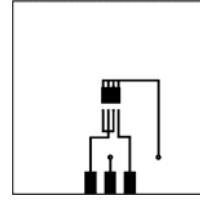
Note 1: Ensure that the channel temperature does not exceed 150°C .

Note 2: (a) Device mounted on a glass-epoxy board (a) (b) Device mounted on a glass-epoxy board (b)



FR-4
25.4 x 25.4 x 0.8
(Unit: mm)

(a)



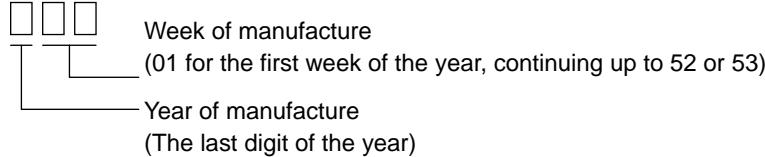
FR-4
25.4 x 25.4 x 0.8
(Unit: mm)

(b)

Note 3: $V_{DD} = 24 \text{ V}$, $T_{ch} = 25^\circ\text{C}$ (initial), $L = 200 \mu\text{H}$, $R_G = 25 \Omega$, $I_{AR} = 26 \text{ A}$

Note 4: Repetitive rating: pulse width limited by maximum channel temperature

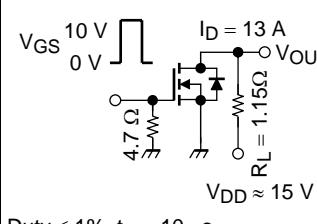
Note 5: * Weekly code: (Three digits)



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Electrical Characteristics (Ta = 25°C)

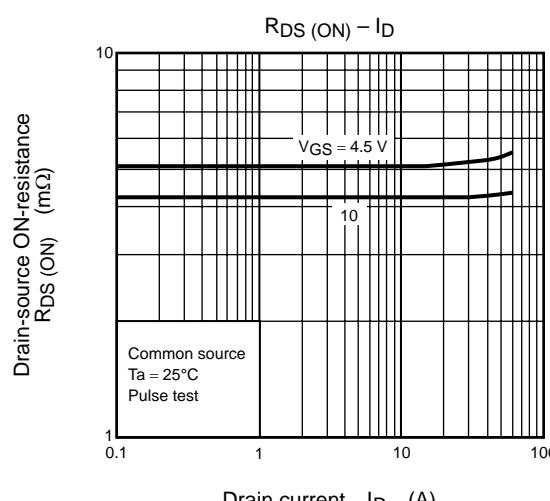
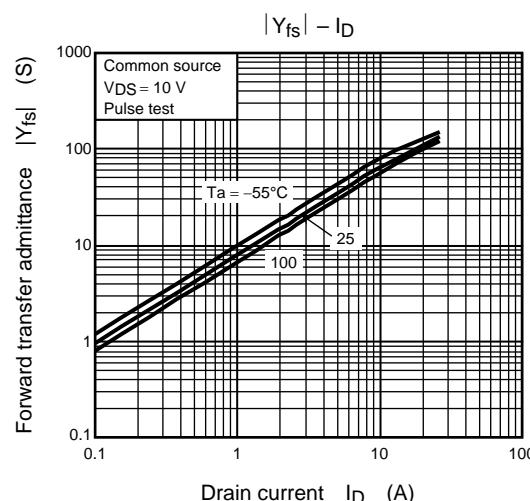
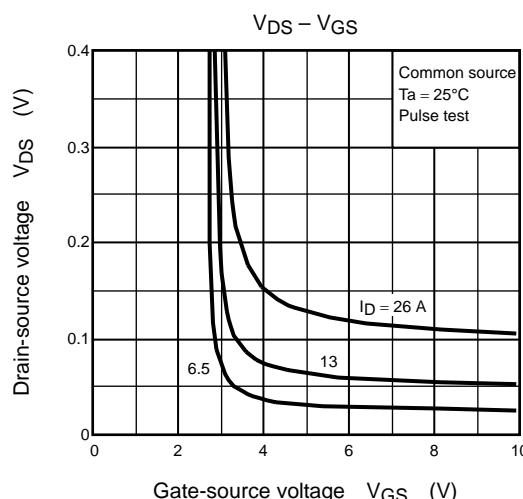
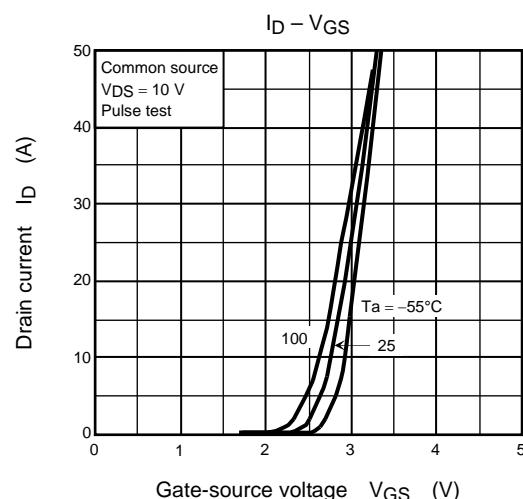
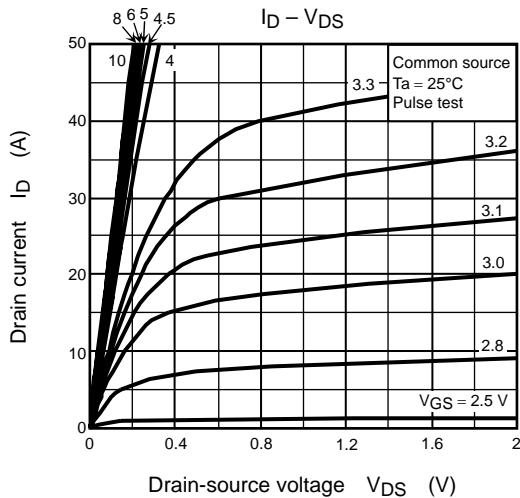
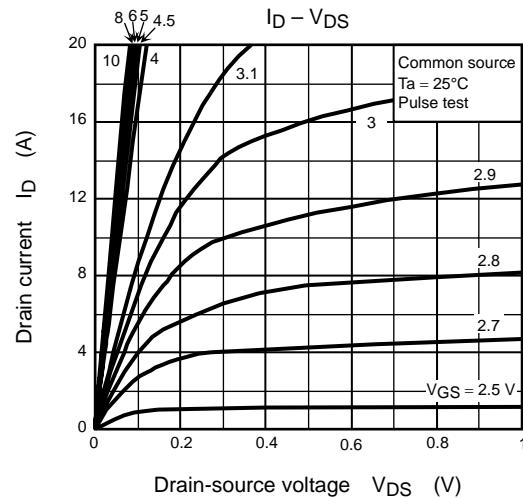
Characteristic	Symbol	Test Condition	Min	Typ.	Max	Unit
Gate leakage current	I _{GSS}	V _{GS} = ±20 V, V _{DS} = 0 V	—	—	±100	nA
Drain cutoff current	I _{DSS}	V _{DS} = 30 V, V _{GS} = 0 V	—	—	10	μA
Drain-source breakdown voltage	V _{(BR) DSS}	I _D = 10 mA, V _{GS} = 0 V	30	—	—	V
	V _{(BR) DSX}	I _D = 10 mA, V _{GS} = -20 V	15	—	—	
Gate threshold voltage	V _{th}	V _{DS} = 10 V, I _D = 0.5 mA	1.3	—	2.3	V
Drain-source ON-resistance	R _{DSS (ON)}	V _{GS} = 4.5 V, I _D = 13 A	—	5.2	7.4	mΩ
		V _{GS} = 10 V, I _D = 13 A	—	4.3	6.4	
Forward transfer admittance	Y _{fs}	V _{DS} = 10 V, I _D = 13 A	40	79	—	S
Input capacitance	C _{iss}	V _{DS} = 10 V, V _{GS} = 0 V, f = 1 MHz	—	2200	2900	pF
Reverse transfer capacitance	C _{rss}		—	140	220	
Output capacitance	C _{oss}		—	440	—	
Gate resistance	r _g	V _{DS} = 10 V, V _{GS} = 0 V, f = 5 MHz	—	3.4	5.1	Ω
Switching time	Rise time	t _r	 V _{GS} 10 V 0 V ID = 13 A 4.7 Ω 1.15 Ω V _{DD} ≈ 15 V Duty ≤ 1%, t _w = 10 μs	—	4.5	—
	Turn-on time	t _{on}		—	12	—
	Fall time	t _f		—	9.8	—
	Turn-off time	t _{off}		—	52	—
Total gate charge (gate-source plus gate-drain)	Q _g	V _{DD} ≈ 24 V, V _{GS} = 10 V, I _D = 26 A	—	35	—	nC
		V _{DD} ≈ 24 V, V _{GS} = 5 V, I _D = 26 A	—	19	—	
Gate-source charge 1	Q _{gs1}	V _{DD} ≈ 24 V, V _{GS} = 10 V, I _D = 26 A	—	6.6	—	
Gate-drain ("Miller") charge	Q _{gd}		—	6.2	—	
Gate switch charge	Q _{SW}		—	9.1	—	

Source-Drain Ratings and Characteristics (Ta = 25°C)

Characteristic	Symbol	Test Condition	Min	Typ.	Max	Unit
Drain reverse current Pulse (Note 1)	I _{DRP}	—	—	—	78	A
Forward voltage (diode)	V _{DSF}	I _{DR} = 26 A, V _{GS} = 0 V	—	—	-1.2	V

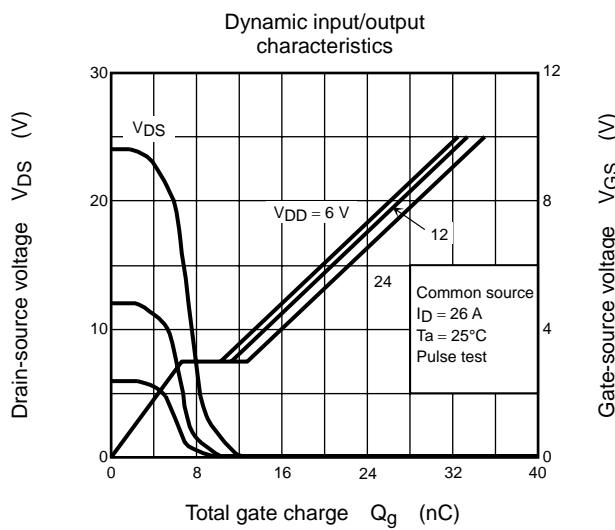
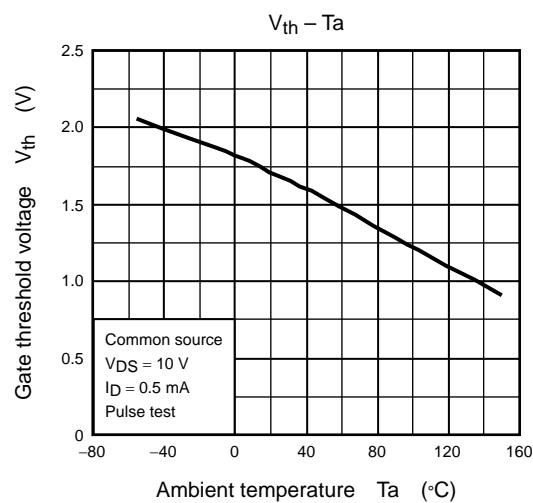
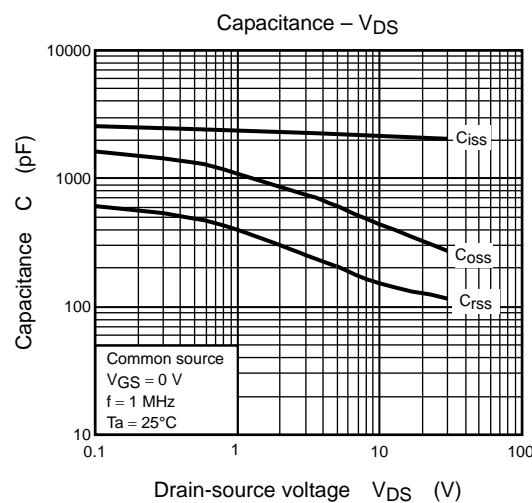
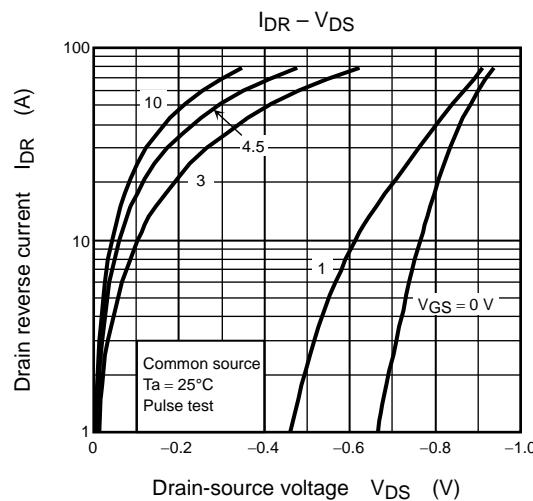
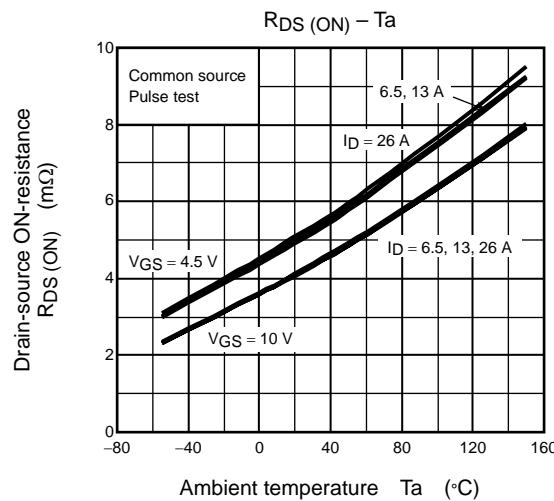
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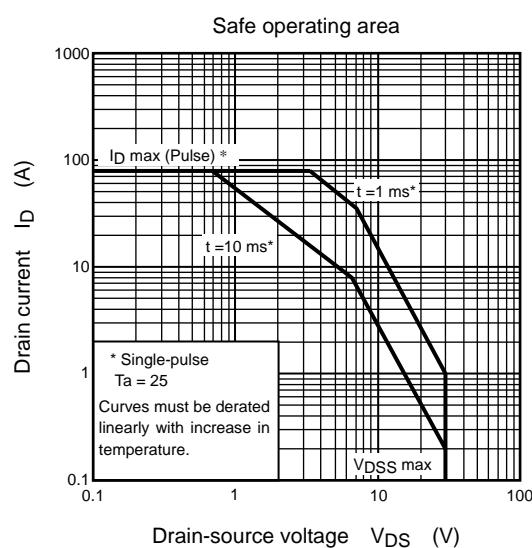
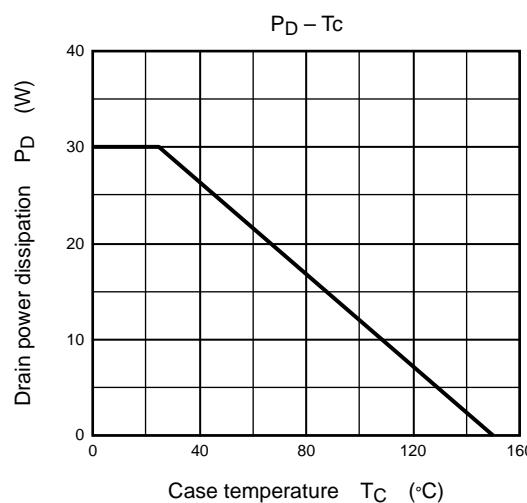
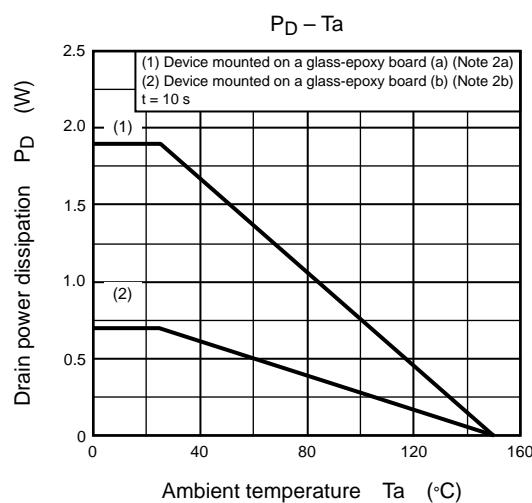
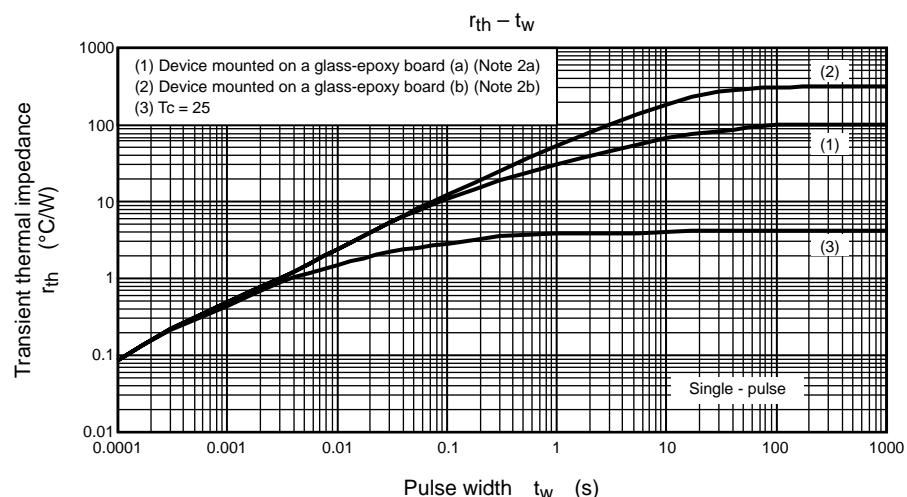
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